



# Voltage Detectors, ME2804 Series

#### **General Description**

ME2804 Series are highly precise, low power consumption voltage detectors, manufactured using NMOS technologies. Detect voltage is extremely accurate with minimal temperature drift. NMOS output configurations are available.

#### Features

- Highly accuracy: ±1% (-VDET>1.5V)
- Low power consumption:

TYP 0.7uA (VIN=3.5V, -VDET=2.0V)

Detect voltage range:

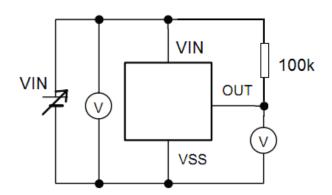
1.0V~6.5V in 0.1V increments

- Operating voltage range: 0.7V~7V
- Detect voltage temperature characteristics: TYP±100ppm/°C
- Output configuration: NMOS

### **Typical Application**

- Microprocessor reset circuitry
- Memory battery back-up circuits
- Power-on reset circuits
- Power failure detection

### **Typical Application Circuit**

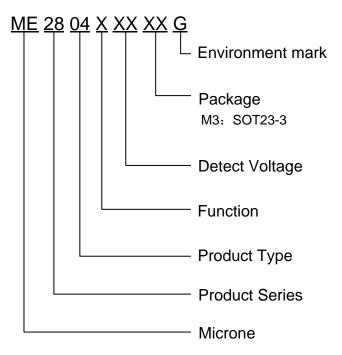


# • 3-pin SOT23-3

Package



### **Selection Guide**



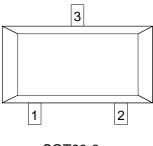
product series	product description			
ME2804A10M3G	V <sub>DET</sub> =1.0V; Rising edge detection; Package: SOT23-3			
ME2804A33M3G	V <sub>DET</sub> =3.3V; Rising edge detection; Package: SOT23-3			

#### NOTE:

- 1. At present ,there are thirteen kinds of voltage value: 1.0V、1.1V、1.2V、1.3V、1.4V、1.45V、1.8V、2.2V、 2.5V、2.7V、3.0V、3.3V、3.8V。
- 2. If you need other voltage or package, please contact our sales staff.



# **Pin Configuration**

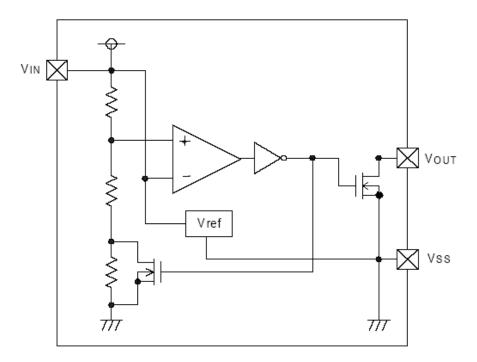


SOT23-3

# Pin Assignment

Pin Number SOT23-3	Pin Name	Functions	
2	GND	Ground	
1	VOUT	Output Voltage	
3	VIN	Input Voltage	

# **Block Diagram**





# **Absolute Maximum Ratings**

Parameter		Symbal	Ratings	Units
V <sub>IN</sub> Input Voltage		V <sub>IN</sub>	8	V
Output Current		I <sub>OUT</sub>	50	mA
Output Voltage	NMOS	V <sub>OUT</sub>	GND-0.3~V <sub>IN</sub> +0.3	V
Internal Power Dissipation	SOT23-3	Pd	540	mW
Thermal resistance (Junction to air)	SOT23-3	θ <sub>JA</sub>	230	°C/W
Operating Ambient Temperature		T <sub>Opr</sub>	-40~+85	°C
Maximum junction temperature		TJ	-40~+150	°C
Storage Temperature		T <sub>stg</sub>	-55~+150	°C
Soldering temperature and time		T <sub>solder</sub>	<b>260℃, 10s</b>	
ESD		MM	400	V
		HBM	4000	V

### **Electrical Characteristics**

(-V<sub>DET</sub>(S)=1.0V to  $6.5V\pm1\%$  ,Ta=25<sup>O</sup>C ,unless otherwise noted)

Parameter	Symbol	Conditions	Min.	Тур	Max.	Units
Detect Voltage	-VDET	-VDET (S) ≦1.5V	-VDET(S) ×0.98	-VDET(S)	-VDET(S) ×1.02	V
		-VDET (S) >1.5V	-VDET(S) ×0.99	-VDET(S)	-VDET(S) ×1.01	
Hysteresis Range	VHYS	-	0.03	0.06	0.1	V
Supply Current	ISS	VIN=2.0V (1.0V-1.5V)	-	0.7	1	uA
		VIN =3.5V (1.6V-2.0V)	-	0.7	1	
		VIN=4.5V (2.1V-3.9V)	-	1.2	2	
		VIN =6.0V (4.0V-5.6V)	-	1.1	2	
		VIN=7.0V (5.7V-6.5V)	-	1.0	2	
Output Current	lout N-ch	VDS=0.5V VIN =0.7V	0.01	0.14	-	mA
Operating voltage	VIN	-	0.7	-	7	V
Responding time	tpLH		-	-	60	us
Temperature characteristics	$\frac{\Delta - VDET}{\Delta Ta \times - VDET}$	∆Ta = -40°C~85°C	-	±100	±350	ppm/°C

Note: 1, -VDET(S) : Specified Detection Voltage value

2、-VDET: Actual Detection Voltage value

3、Release Voltage: +VDET=-VDET+VHYS

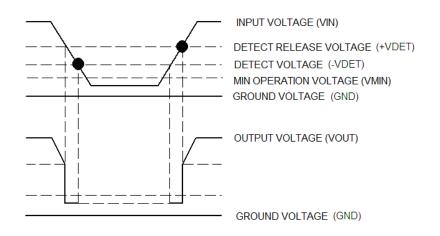


### **Functional Description:**

- 1. When input voltage ( $V_{IN}$ ) rises above detect voltage (–VDET), output voltage ( $V_{OUT}$ ) will be equal to  $V_{IN}$ .
- When input voltage (V<sub>IN</sub>) falls below detect voltage (–VDET), output voltage (V<sub>OUT</sub>) will be equal to the ground voltage (GND) level.
- 3. When input voltage  $(V_{IN})$  falls to a level below that of the minimum operating voltage  $(V_{MIN})$ , output will become unstable. In this condition,  $V_{IN}$  will equal the pulled-up output (should output be pulled-up.)
- 4. When input voltage (V<sub>IN</sub>) rises above the ground voltage (GND) level, output will be unstable at levels below the minimum operating voltage (V<sub>MIN</sub>). Between the VMIN and detect release voltage +VDET) levels, the ground voltage (GND) level will be maintained.
- 5、 When input voltage (V<sub>IN</sub>) rises above detect release voltage (+VDET), output voltage (V<sub>OUT</sub>) will be equal to V<sub>IN</sub>.
- 6. The difference between +VDET and –VDET represents the hysteresis range.

#### **Timing Chart:**

#### ME2804XX:



#### **Directions for use:**

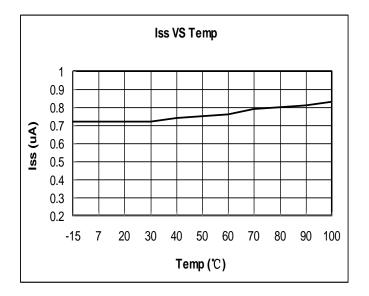
- 1. Please use this IC within the stated maximum ratings. Operation beyond these limits may cause degrading or permanent damage to the device.
- In order to stabilize the IC's operations, please ensure that V<sub>IN</sub> pin's input frequency's rise and fall times are more than several u Sec/V.



### **Type Characteristics**

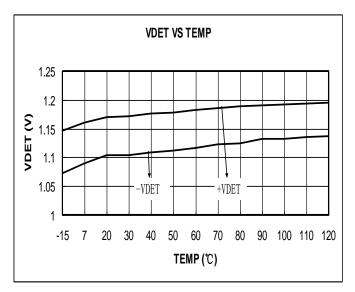
1, Supply Current VS. Ambient Temperature

VIN=2V,-VDET=1.1V

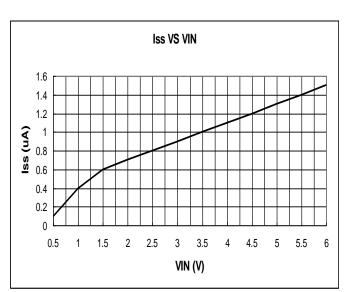


#### 3、Detect, Release Voltage VS. Ambient Temperature

-VDET=1.1V



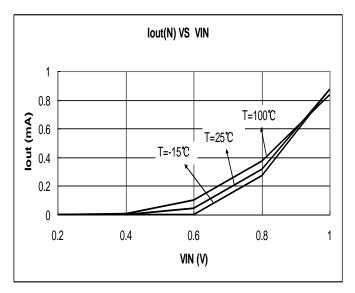
2、Supply Current VS. Input Voltage



-VDET=1.1V (T=25°C)

4、N-ch OUTPUT CURRENT VS. INPUT VOLTAGE

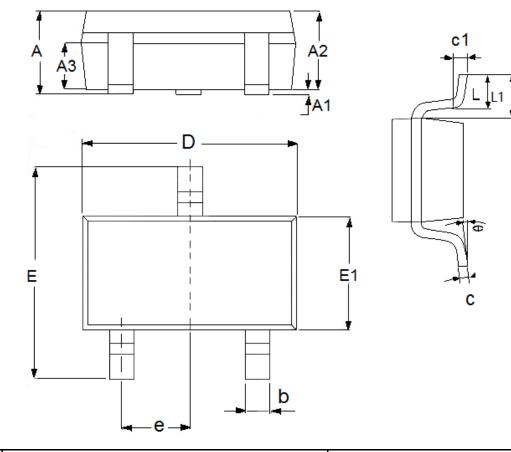
VDS=0.5V -VDET=1.1V





# **Packaging Information**

• Package Type:SOT23-3



DIM -	Millimeters		Inches		
	Min	Мах	Min	Max	
A	1.05	1.45	0.0413	0.0571	
A1	0	0.15	0.0000	0.0059	
A2	0.9	1.3	0.0354	0.0512	
A3	0.6	0.7	0.0236	0.0276	
b	0.25	0.5	0.0098	0.0197	
С	0.1	0.25	0.0039	0.0098	
D	2.8	3.1	0.1102	0.1220	
E	2.6	3.1	0.1023	0.1220	
E1	1.5	1.8	0.0591	0.0709	
е	0.95(TYP)		0.0374(TYP)		
L	0.25	0.6	0.0098	0.0236	
L1	0.59(TYP)		0.0232(TYP)		
θ	0	8°	0.0000	8°	
c1	0.2(TYP)		0.0079(TYP)		



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